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February 2007

±2.5V to ±17V

0.00003% (typ)

0.00003% (typ)

 $2.7 \text{nV}/\sqrt{\text{Hz}}$ (typ)

±20V/µs (typ)

55MHz (typ)

LME49740 **Quad High Performance, High Fidelity Audio Operational** Amplifier

General Description

The LME49740 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49740 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49740 combines extremely low voltage noise density $(2.7 \text{nV}/\sqrt{\text{HZ}})$ with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49740 has a high slew rate of ±20V/µs and an output current capability of ±26mA. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads. The LME49740's outstanding CMRR(120dB), PSRR(120dB), and VOS(0.1mV) give the amplifier excellent operational amplifier DC performance.

The LME49740 has a wide supply range of $\pm 2.5V$ to $\pm 17V$. Over this supply range the LME49740's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49740 is unity gain stable. The Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49740 is available in 14-lead narrow body SOIC and 14-lead plastic DIP. Demonstration boards are available for each package.

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Key Specifications

- Power Supply Voltage Range
- THD+N ($A_V = 1$, $V_{OUT} = 3V_{RMS}$, $f_{INI} = 1 kHz$
- $R_1 = 2k\Omega$
- $R_1 = 600\Omega$
- Input Noise Density
- Slew Rate
- Gain Bandwidth Product
- 140dB (typ) Open Loop Gain (R₁ = 600Ω)
- Input Bias Current
- Input Offset Voltage 0.1mV (typ)
- 0.000009% DC Gain Linearity Error

Features

- Easily drives 600Ω loads
- Optimized for superior audio signal fidelity
- Output short circuit protection
- PSRR and CMRR exceed 120dB (typ)
- SOIC and DIP packages

Applications

- Ultra high quality audio amplification
- High fidelity preamplifiers
- High fidelity multimedia
- State of the art phono pre amps
- High performance professional audio
- High fidelity equalization and crossover networks
- High performance line drivers
- High performance line receivers
- High fidelity active filters



.ME49740 Quad High Performance, High Fidelity Audio Operational Amplifier





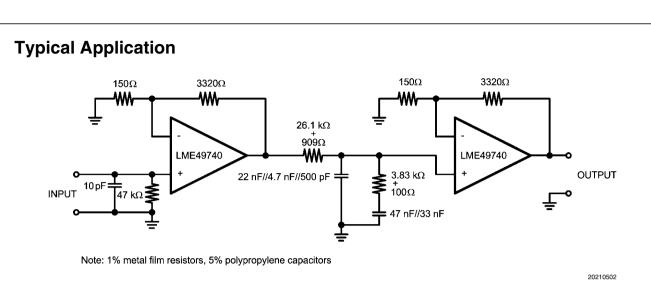
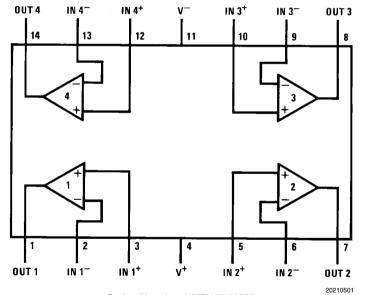


FIGURE 1. Passively Equalized RIAA Phono Preamplifier

Connection Diagram



Order Number LME49740MA See NS Package Number — M14A Order Number LME49740NA See NS Package Number — N14A

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Absolute Maximum Ratings (Notes 1, 2) If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.		ESD Susceptibility (Note 4) ESD Susceptibility (Note 5) Junction Temperature Thermal Resistance	2000V 200V 150°C
Power Supply Voltage (V _S = V ⁺ - V ⁻) Storage Temperature	36V –65°C to 150°C	θ _{JA} (MA) θ _{JA} (NA) Temperature Range	107°C/W 74°C/W
Input Voltage Output Short Circuit (Note 3) Power Dissipation	(V-) - 0.7V to (V+) + 0.7V Continuous Internally Limited	$T_{MIN} \le T_A \le T_{MAX}$ Supply Voltage Range	$-40^{\circ}C \le T_A \le 85^{\circ}C$ $\pm 2.5V \le V_S \le \pm 17V$

$\label{eq:Electrical Characteristics} \mbox{(Notes 1, 2)} \quad \mbox{The following specifications apply for $V_S = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1kHz$, f_{IN}

and $T_A = 25C$, unless otherwise specified.

			LME49740		
Symbol	Parameter	Conditions	Typical	Limit	Units
-			(Note 6)	(Notes 7, 8)	(Limits)
		$A_V = 1, V_{OUT} = 3V_{RMS}$			
THD+N	Total Harmonic Distortion + Noise	$R_L = 2k\Omega$	0.00003		% (max)
		R _L = 600Ω	0.00003	0.00009	% (max)
IMD	Intermodulation Distortion	A _V = 1, V _{OUT} = 3V _{RMS} Two-tone, 60Hz & 7kHz 4:1	0.00005		% (max)
GBWP	Gain Bandwidth Product		55	45	MHz (min
SR	Slew Rate		±20	±15	V/µs (min)
FPBW	Full Power Bandwidth	V _{OUT} = 1V _{P-P} , -3dB referenced to output magnitude at f = 1kHz	10		MHz
t _s	Settling time	A _V = 1, 10V step, C _L = 100pF 0.1% error range	1.2		μs
	Equivalent Input Noise Voltage	f _{BW} = 20Hz to 20kHz	0.34	0.65	μV_{RMS}
e _n		f = 1kHz	2.7	4.7	nV/√Hz
	Equivalent Input Noise Density	f = 10Hz	6.4		nV/√Hz
		f = 1kHz	1.6		pA / √Hz
i _n	Current Noise Density	f = 10Hz	3.1		pA / √Hz
V _{OS}	Offset Voltage		±0.1	±0.7	mV (max)
$\Delta V_{OS} / \Delta Temp$	Average Input Offset Voltage Drift vs Temperature	40°C ≤ T _A ≤ 85°C	0.2		μV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	ΔV _S = 20V (Note 9)	120	110	dB (min)
ISO _{CH-CH}	Channel-to-Channel Isolation	f _{IN} = 1kHz	118		dB
ICCCH-CH		f _{IN} = 20kHz	112		dB
I _B	Input Bias Current	V _{CM} = 0V	10	72	nA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	–40°C ≤ T _A ≤ 85°C	0.1		nA/°C
I _{OS}	Input Offset Current	$V_{CM} = 0V$	11	65	nA (max)
V _{IN-CM}	Common-Mode Input Voltage Range		+14.1 -13.9	(V+)–2.0 (V-)+2.0	V (min) V (min)
CMRR	Common-Mode Rejection	-10V <v<sub>CM<10V</v<sub>	120	110	dB (min)
Z _{IN}	Differential Input Impedance		30		kΩ
	Common Mode Input Impedance	-10V <v<sub>CM<10V</v<sub>	1000		MΩ
A _{VOL}		–10V <v<sub>OUT<10V, R_L = 600Ω</v<sub>	140		dB (min)
	Open Loop Voltage Gain	$-10V < V_{OUT} < 10V, R_{L} = 2k\Omega$	140		dB (min)
		$-10V < V_{OUT} < 10V, R_{L} = 10k\Omega$	140	125	dB (min)

			LME	LME49740	
Symbol	Parameter	Conditions	Typical	Limit	Units (Limits)
			(Note 6)	(Notes 7, 8)	
V _{OUTMAX} Maximum Output Voltage Swing		R _L = 600Ω	±13.6	±12.5	V (min)
	$R_L = 2k\Omega$	±14.0		V (min)	
		$R_L = 10k\Omega$	±14.1		V (min)
I _{OUT}	Output Current	R _L = 600Ω, V _S = ±17V	±26	±23	mA (min
I _{OUT-CC} Short Circuit Current	Short Circuit Current		+30		mA
		-38		mA	
		f _{IN} = 10kHz			
R _{OUT} Output Impedance	Output Impedance	Closed-Loop	0.01		Ω
		Open-Loop	13		Ω
C _{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%
I _s	Total Quiescent Current	I _{OUT} = 0mA	18.5	20	mA (max

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Note 2: Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 3: Amplifier output connected to GND, any number of amplifiers within a package.

Note 4: Human body model, 100pF discharged through a 1.5k $\!\Omega$ resistor.

Note 5: Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50Ω).

Note 6: Typical specifications are specified at +25°C and represent the most likely parametric norm.

Note 7: Tested limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 8: Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.

Note 9: PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V. PSRR = |20log($\Delta V_{OS}/\Delta V_{S}$)|.

Typical Performance Characteristics THD+N vs Output Voltage $V_{CC} = 15V, V_{EE} = -15V, R_L = 2k\Omega$ 0.01 0.005 0.002 0.001 THD+N (%) 0.0005 0.0002 0.0001 0.00005 0.00002 0.00001 10m 100m 1 10 20 $V_{\rm RMS}$ 20210515 **THD+N vs Frequency** $V_{CC} = 15V$, $V_{EE} = -15V$, $R_L = 2k\Omega$, $V_{OUT} = 3V_{RMS}$ 0.01 0.005 0.002 0.001 THD+N (%) 0.0005 ╢ 0.0002 0.0001 0.00005 0.00002 0.00001 20 50 100 200 500 1k 2k 5k 10k 20k FREQUENCY (Hz) 20210511 **THD+N vs Frequency** $V_{CC} = 15V, V_{EE} = -15V, R_{L} = 600\Omega, V_{OUT} = 3V_{RMS}$ 0.01 0.005 0.002 0.001 THD+N (%) 0.0005 0.0002 0.0001

0.00005

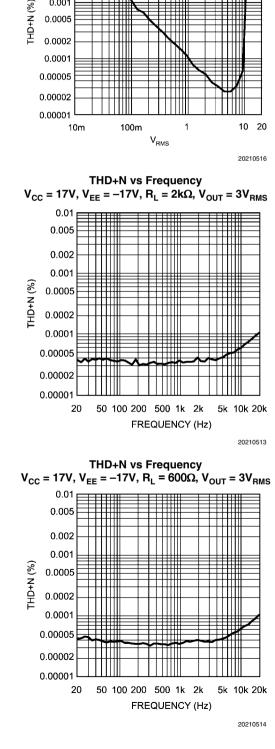
0.00002

0.00001

20

50 100 200 500 1k 2k

FREQUENCY (Hz)



THD+N vs Output Voltage

 $V_{CC} = 17V, V_{EE} = -17V, R_L = 2k\Omega$

0.01

0.005

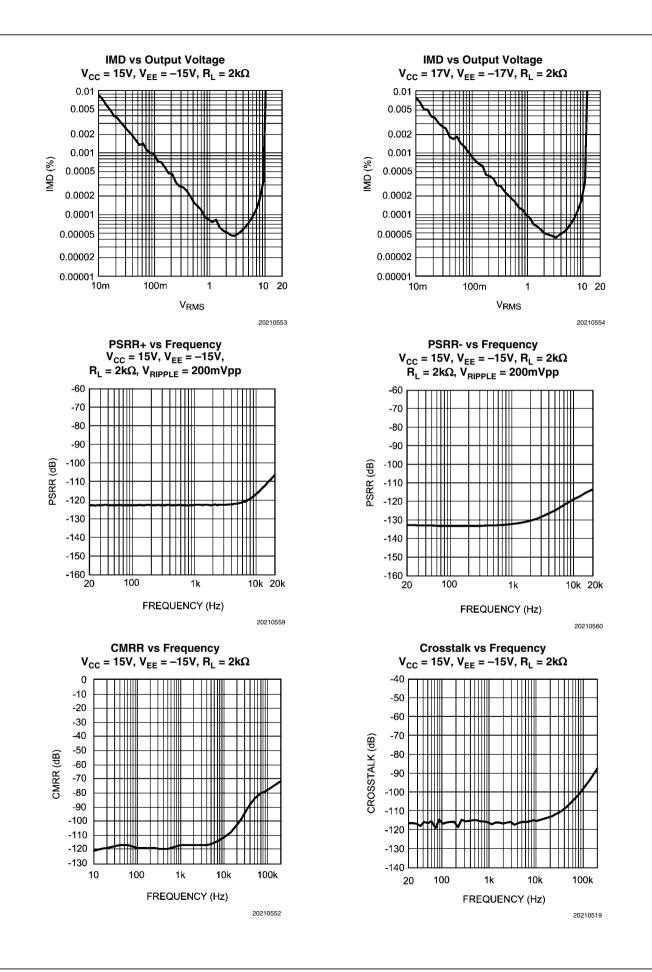
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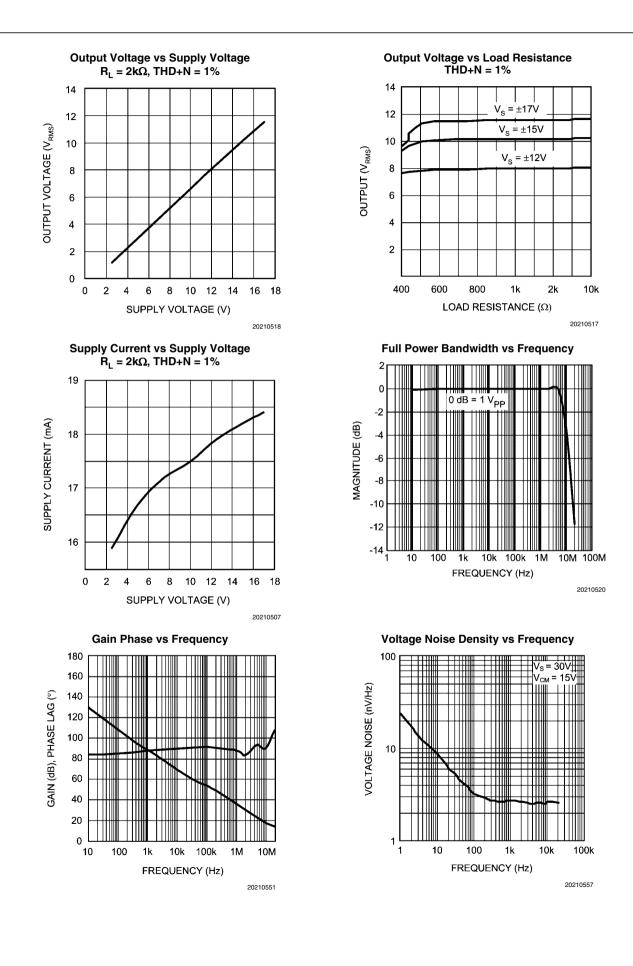
5k 10k 20k

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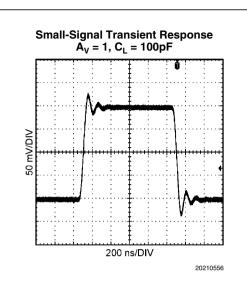


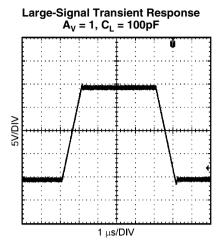












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Application Information

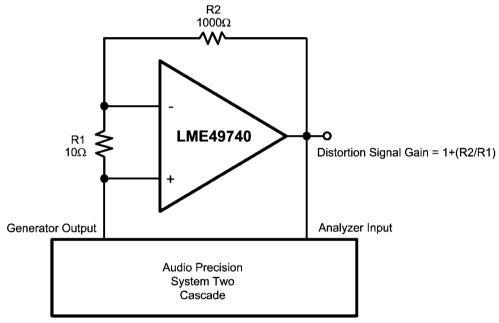
DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49740 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49740's low residual distortion is an input referred internal error. As shown in Figure 2, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting

inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 2.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



Actual Distortion = AP Value/100

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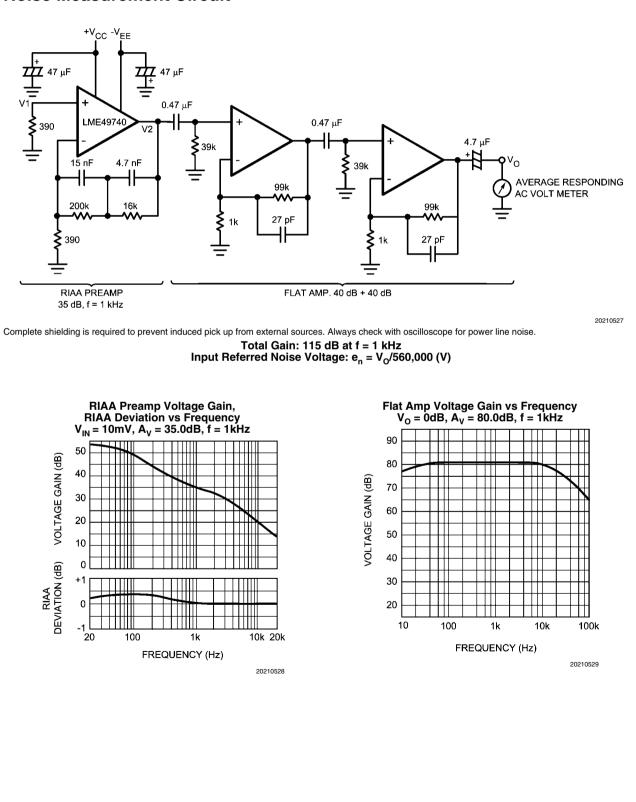
FIGURE 2. THD+N and IMD Distortion Test Circuit

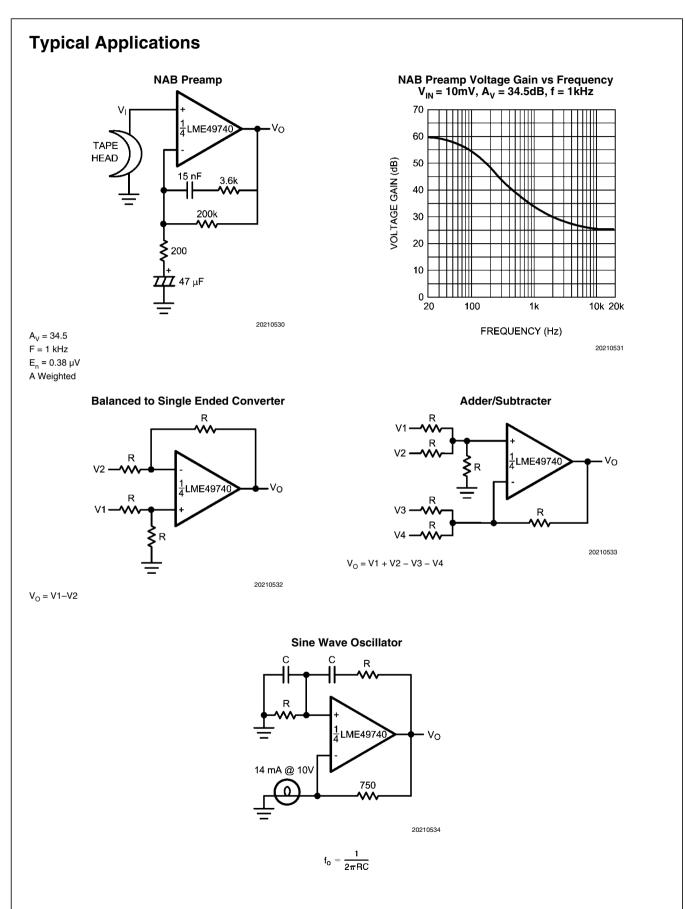
Application Hints

The LME49740 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

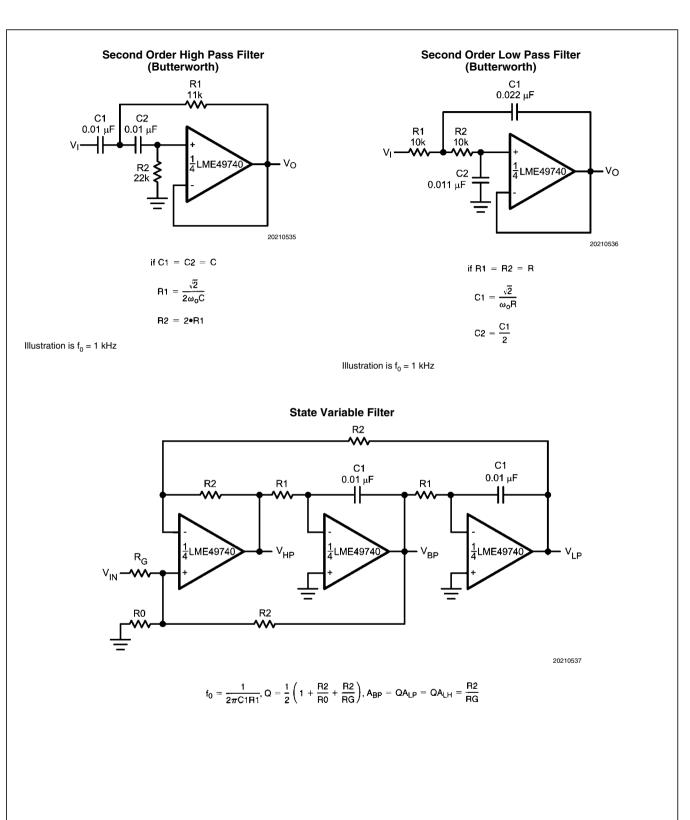
Noise Measurement Circuit

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.



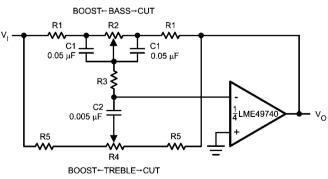






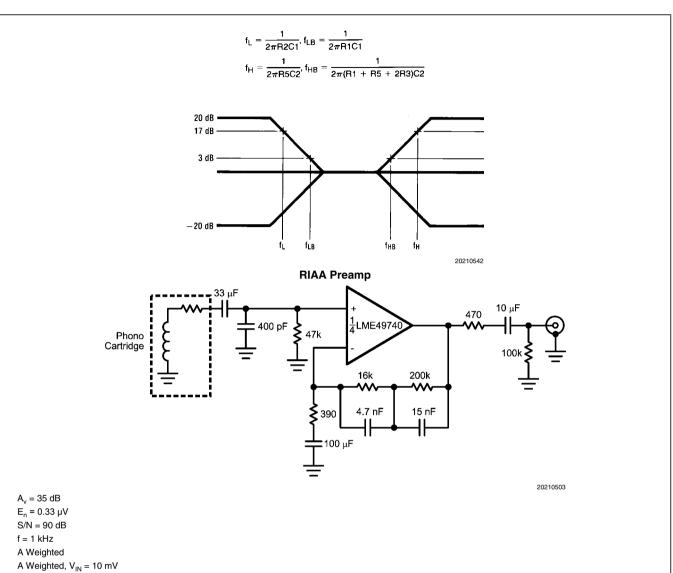
AC/DC Converter C1 10 μF R5 20k 11 R2 R3 R4 20k 10k 20k M ۸. L R1 20k D1 ·1S1588 **** \ VIN 14 LME49740 $V_O = |\overline{VIN}|$ $\frac{1}{4}$ LME49740 **7** D2 -1S1588 R6 **≹** ^{R7} 6.2k Ş 15k 20210538 Line Driver 2 Channel Panning Circuit (Pan Pot) 3.41R1 51k R2 Ŵ - Vcc R1 15k R1 15k R3 R1 \sim Vi 1 4LME49740 Q1 14LME49740 Vo1 R9 **k** R7 **k** 33 ٧o 0.707R1 ٧ŀ **k** R8 **3**3 10k ¥ R5 10k BIAS Q2 R6 R1 15k R1 15k $\frac{1}{4}$ LME49740 V_{O2} ۸, -VEE 20210540 3.41R1 51k W 20210539

Tone Control



20210541

LME49740



@f = 1 kHz

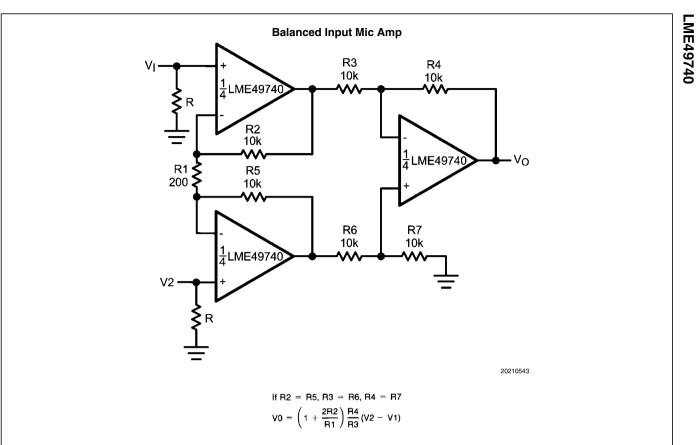
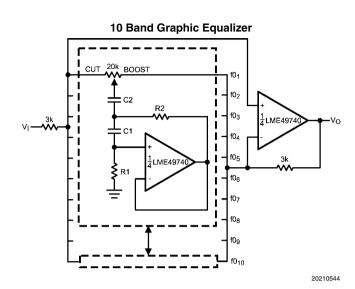


Illustration is:

V0 = 101(V2 - V1)



fo (Hz) C₁ C_2 R₁ R_2 32 0.12µF 4.7µF 75kΩ 500Ω 64 0.056µF 3.3µF 68kΩ 510Ω 125 0.033µF 62kΩ 510Ω 1.5µF 250 0.015µF 470Ω 0.82µF 68kΩ 8200pF 500 0.39µF 62kΩ 470Ω 3900pF 68kΩ 470Ω 1k 0.22µF 2000pF 2k 0.1µF 68kΩ 470Ω 1100pF 4k 0.056µF 62kΩ 470Ω 8k 510pF 0.022µF 68kΩ 510Ω 330pF 16k 0.012µF $51 k\Omega$ 510Ω

Note 10: At volume of change = $\pm 12 \text{ dB}$

Q = 1.7

Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2-61

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Description

1.0 02/28/07 Initial WEB release.

Date

Revision History

Rev

A .340±.004 [8.64±0.1] H Γ В R.007±.001 [0.18±0.02] R.009±.001 [0.23±0.02] .154±.004 [3.91±0.1] .236±.008 [5.99±0.2] 0° - 8'

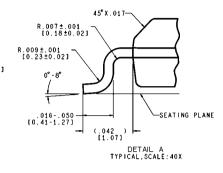
Physical Dimensions inches (millimeters) unless otherwise noted

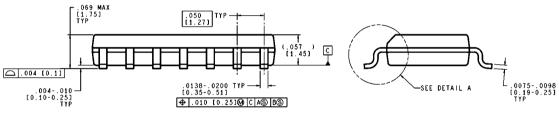
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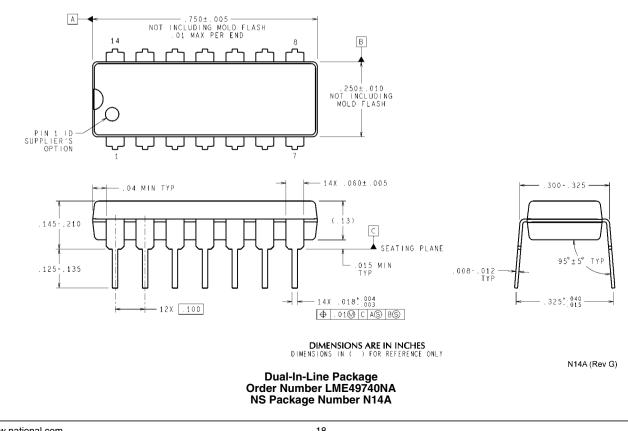
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M14A (Rev J)

Dual-In-Line Package Order Number LME49740MA NS Package Number M14A



ME49740 Quad High Performance, High Fidelity Audio Operational Amplifier

Notes

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